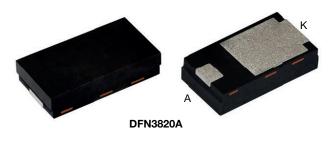


Vishay General Semiconductor

# Surface-Mount TMBS® (Trench MOS Barrier Schottky) Rectifier



Anode O Cathode

## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2.0 A			
V <sub>RRM</sub>	200 V			
I <sub>FSM</sub>	50 A			
$V_F$ at $I_F$ = 1.0 A ( $T_J$ = 125 °C)	0.60 V			
T <sub>J</sub> max.	175 °C			
Package	DFN3820A			
Circuit configuration	Single			

### FEATURES

- Low profile package typical height of 0.88 mm Available
- Leadless DFN package with side-wettable flanks suitable for customer AOI (Automatic Optical Inspection)
- Trench MOS Schottky technology
- Low power losses, high efficiency
- Low forward voltage drop
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  Automotive ordering code; base P/NHM3
- Compatible to SMP (DO-220AA) package case outline
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

## **TYPICAL APPLICATIONS**

For use in low voltage, high frequency inverters, freewheeling, DC/DC converters, and polarity protection applications.

### **MECHANICAL DATA**

Case: DFN3820A

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

Polarity: color band denotes the cathode end

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER	SYMBOL	V2N22	UNIT	
Device marking code		V2D		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	200	V	
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub> <sup>(1)</sup>	2	А	
	I <sub>F(AV)</sub> <sup>(2)</sup>	1.5	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	IFSM	50	А	
Operating junction and storage temperature range	T <sub>J</sub> <sup>(3)</sup>	-40 to +175	°C	
Operating junction and storage temperature range	T <sub>STG</sub>	-55 to +175	°C	

#### Notes

<sup>(1)</sup> With infinite heatsink

(2) Free air, mounted on FR4 PCB, 2 oz., standard footprint

 $^{(3)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

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RoHS

COMPLIANT HALOGEN

FREE

V2N22



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ELECTRICAL CHARACTERISTICS (T <sub>J</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT
	I <sub>F</sub> = 1.0 A		0.74	-		
In standard second for worked works as	I <sub>F</sub> = 2.0 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.80	0.85	v
Instantaneous forward voltage	I <sub>F</sub> = 1.0 A	T 105 %O		0.60	-	
	$T_{J} = 125 \text{ °C}$		0.66	0.72		
Reverse current	V 160 V	T <sub>J</sub> = 25 °C	I <sub>B</sub> <sup>(2)</sup>	0.00015	-	mA
	v <sub>R</sub> = 100 v	T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C		0.14	-	
		T <sub>J</sub> = 25 °C T <sub>J</sub> = 125 °C	IR (-/	-	0.04	IIIA
	v <sub>R</sub> = 200 v	T <sub>J</sub> = 125 °C		0.3	1.0	
Typical junction capacitance	4.0 V, 1 MH	4.0 V, 1 MHz		110	-	pF

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise specified)				
PARAMETER	SYMBOL	TYP.	MAX.	UNIT
Thermal resistance	R <sub>0JA</sub> (1)(2)	140	175	°C/W
	R <sub>0JM</sub> <sup>(3)</sup>	6	7.5	0/11

#### Notes

 $^{(1)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

(2) Thermal resistance junction-to-ambient to follow JEDEC® 51-2A, device mounted on FR4 PCB, 2 oz., standard footprint

<sup>(3)</sup> Thermal resistance junction-to-mount to follow JEDEC<sup>®</sup> 51-14 transient dual interface test method (TDIM)

## **ORDERING INFORMATION TABLE**

**Device code** V 2 2 Ν 2

3

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		-	
-	Vishay	IMBS	product

3

- Current rating (2 = 2 A) 2
  - Package type (N = DFN3820A)
- 4 Voltage rating (2 = 200 V)
  - TMBS generation option (2 = gen 2)

4

- Quality grade (H = AEC-Q101 qualified, = industry grade)
- Material / Environmental category (M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

2

5

н

6

**M**3

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V2N22-M3/H	0.023	Н	3500	7" diameter plastic tape and reel		
V2N22-M3/I	0.023	I	14 000	13" diameter plastic tape and reel		
V2N22HM3/H <sup>(1)</sup>	0.023	н	3500	7" diameter plastic tape and reel		
V2N22HM3/I <sup>(1)</sup>	0.023	I	14 000	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

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# **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

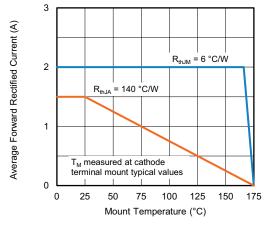


Fig. 1 - Maximum Forward Current Derating Curve

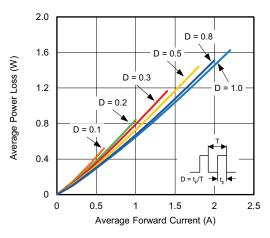


Fig. 2 - Forward Power Loss Characteristics

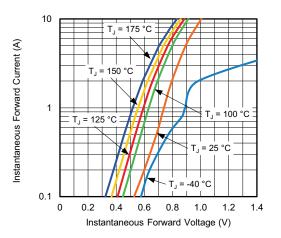


Fig. 3 - Typical Instantaneous Forward Characteristics

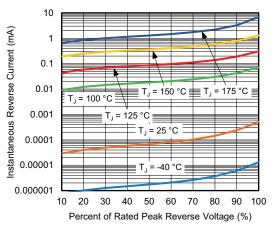


Fig. 4 - Typical Reverse Characteristics

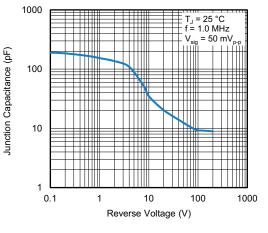


Fig. 5 - Typical Junction Capacitance

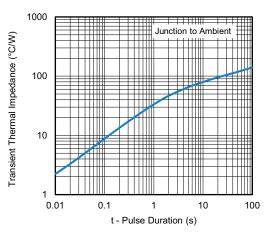


Fig. 6 - Typical Transient Thermal Impedance

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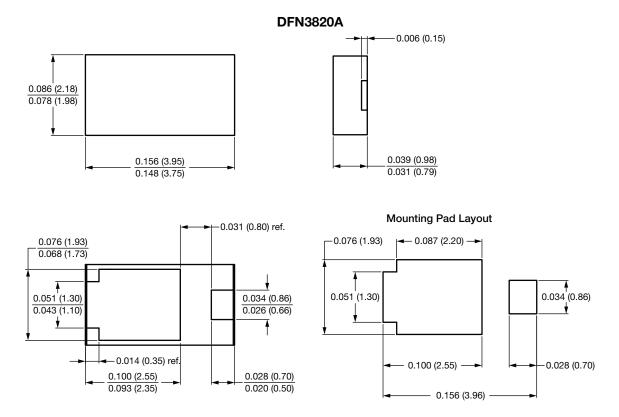


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**ISHAY** 

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## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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